NSN 5961-01-019-1056

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-019-1056 **Inclosure Material:** Metal all transistor **Overall Length:** 1.573 inches all transistor **Overall Height:** 0.328 inches all transistor Overall Width: 1.050 inches all transistor **Mounting Facility Quantity:** 2 all transistor **Internal Configuration:** Junction contact all transistor **Internal Junction Configuration:** Npn all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Unthreaded hole all transistor **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 400.0 collector to base voltage, dc all transistor and 400.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 1.00 amperes source cutoff current all transistor and 2.00 amperes source cutoff current all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction all transistor **Precious Material And Location:** Terminals plated gold **Test Data Document:** 73030-729319 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin all transistor and 1 case all transistor Shelf Life: N/a **Unit Of Measure:**

A110a0

No Fiig:

Demilitarization: